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Transition from a waveguide to a microstrip

1, field of imention

The present invention relates to a transition from a waveguide to a and more farticularly, To a microstrip, wherein the microstrip extending on a substrate projects in 9 through an opening into indiwaveguide and a ground line associated with there with the microstrip contacts the waveguide wall.

Pescription of the related art

Such Atransition from a waveguide to a microstrip is known from US

surface on the opposite substrate aide which contacts the waveguide wall.

One weak point of transitions between a waveguide and a contact strip designed in this way was reflection attenuation which is frequently too low

and-also a transmission attenuation which is too high. 20

What is needed is ".

It is the underlying object of the invention to provide a transition of the kind-first-mentioned which has the highest possible reflection attenuation and the lowest possible transmission attenuation.

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Advantages of the Invention_

Summary of the Invention

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In accordance with ciaim 1, the ground line associated with the microstrip ractuals consists of a plurality of ground surfaces superimposed on one another all of which all contact one another by marks of through-contacts in the a substrate. The multi-layer ground line produces a more favorable field conversion from the microstrip to the waveguide, a hereby a high reflection attenuation and a low transmission attenuation arises for the transition.

Advantageous further developments of the invention can be seen from the dependent claims:

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Since a througholating is provided in the substrate at the end of the which thus microstrip Acting as an antenna and projecting into the waveguide, the transition bandwidth becomes larger. is an larged.

To be able to make a good contact between the ground line and the waveguide wall, it is expedient for ground surfaces to be applied to the substrate and both sides next to the microstrip and for these ground surfaces to be in contact with the other ground surfaces superimposed on one another in the substrate via through contacts (vias). Advantageously, the substrate is fixed by at least one screw on a support on the waveguide walls with the screw being guided through the ground surface and an electrical contact being made between the sand the support.

A low transmission attenuation is achieved in that the at least one screw having

25 lies with its head on one of the ground surfaces applied to the upper Side of the substrate side at the side next to the microstrip and in that a conductive that ribbon which is connected to the waveguide wall, is clamped between the screw head and the ground surface. Alternatively to this, at least one

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conductive elastic body ear be inserted between one of the two ground surfaces located to the side of the microstrip and a projection of the waveguide wall projecting over the ground surfaces. Moreover a conductive elastic body can be pressed a between the head of the at least one screw and the projection of the waveguide wall.

Drawing

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The invention will be described in more detail in the following with reference to a plurality of embodiments shown in the drawing. There are shown:

Figure 1 a perspective illustration of a transition from a waveguide to a microstrip;

Figure 2 a longitudinal section A-A through the transition; and Figure 3 a cross-section B-B through the transition.

20 Description of embodiments

Detailed Description of Helmantion

As-can be seen from the perspective schematic diagram in Figure 1, a Have allow two a microstrip 2 extends on a multi-layer substrate 1. An opening 4 is located in a side wall of a waveguide 3 and a tongue 5 located at the substrate 1, portion Microstrip 2 projects through it into the waveguide 3. The excipt the waveguide 2 which extending on the tongue 5 actors and antenna 6 for coupling the Which couples a waveguide field to the microstrip and/or vice versa.

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Now, Additionally referring to there is shown in more detail in Figures, 2 and 3 two ground surfaces 7 and 8, which are applied to the upper substrate side next to the microstrip? and, in addition, a plurality of ground surfaces are superimposed on one another within the multi-layer substrate and all have the same ground potential.

- 5 The cross-section B-B, through the waveguide 3 into the substrate 1, shown in Figure 3 shows the multi-layer ground surfaces 9 within the substrate 1.
- ground surfaces 7 and 8 at both sides of the microstrip 2. These ground surfaces 7 and 8 on the upper substrate side are connected in an electrically conductive manner by a plurality of through contacts 10 to the other ground surfaces 9 superimposed on one another within the substrate 1. The positions and spacings of the through contacts 10 are selected such that a field propagation, into the intermediate areas between the ground surfaces of the multi-layer substrate I is prevented, since the function of circuits arranged in the individual substrate layers could are thereby be interfered with.
- The ground surfaces 9 of the substrate 1 preferably project some tenths of the value of a millimeter into the waveguide 3, in order to increase the positional tolerance of the substrate 1 with respect to the waveguide 3. The field configuration beneath the microstrip 2 in the waveguide 3 closely depends on the position of the ground surfaces 9. If the position of the substrate 1 is now slightly changed, then the field remains unchanged due to the positional tolerance of the ground surfaces 9. At an operational frequency of, for example, 10 GHz, a penetration depth of the ground surfaces 9 into the waveguide 3 of 0.5 1.0 mm is appropriate.

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The multi-layer substrate 1 forms a larger virtual ground, whereby a field configuration arises which is better transformed into a waveguide wave. The field is namely shaped more intensely into a field component of the fundamental wave type of the waveguide by the larger expansion of the ground (due to the many ground surfaces stacked on top of one another) in the direction of the broad side of the waveguide 3.

It can be seen from Figures 2 and 3 that a throughplating 11 is provided at the end of the antenna 6 of the microstrip 2 extending on the substrate tongue 5. This Throughplating 11 at the end of the antenna 6 of the microstrip results in a broadening of the frequency band of the transition from the waveguide 3 to the microstrip 2. The through contact 11, at the end of the antenna 6 also becomes larger due to the thicker design of the substrate 1, which contributes to a more favorable conversion of the microstrip field into the waveguide field.

The Substrate I is fixed to a Support 14 beneath the Opening 14 and

starting from the waveguide wall by means of at least one screw, there being

are two screws 12 and 13 in the embodiment shown in Figure 2. In this connection, the Screws 12 and 13 lie with their heads on the ground surfaces 7 and 8 applied to the side next to the microstrip 2 and thus serews 13 make an electrical contact between the ground surfaces 7 and 8 and the ground surfaces 9 superimposed on one another in the substrate 1 and

the waveguide wall 14. Since a contact is additionally made between the ground lines 7 and 8 applied to the upper side of the substrate 1, and the waveguide wall the transmission attenuation of the transition is reduced.

This contact can, as shown in Figure 2, be made by two conductive

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ribbons 15 and 16, which are clamped at one end between the reads of the screws 12 and 13 and the conductive surfaces 7 and 8 and attricin other end in the parting plane 17 of the waveguide 3, consisting of two half shells.

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effecting

Figure 3 shows another variant for the contact of the ground surfaces 718 and screws 1213 with the waveguide wall. Here, the waveguide 3 has a wall projection 18 above its opening 4 which projects over the ground surfaces 7 and 8 on the upper side of the substrate 1. One or more conductive elastic bodies 19 are clamped between the ground surfaces 7 and 8 on the upper substrate side and the wall projection 18. One or more conductive elastic bodies 20 can also be pressed between the heads of the screws 12 and 13 and the wall projection 18.

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